

Noise Hit Generation for EICrecon

Minjung Kim (UC Berkeley)

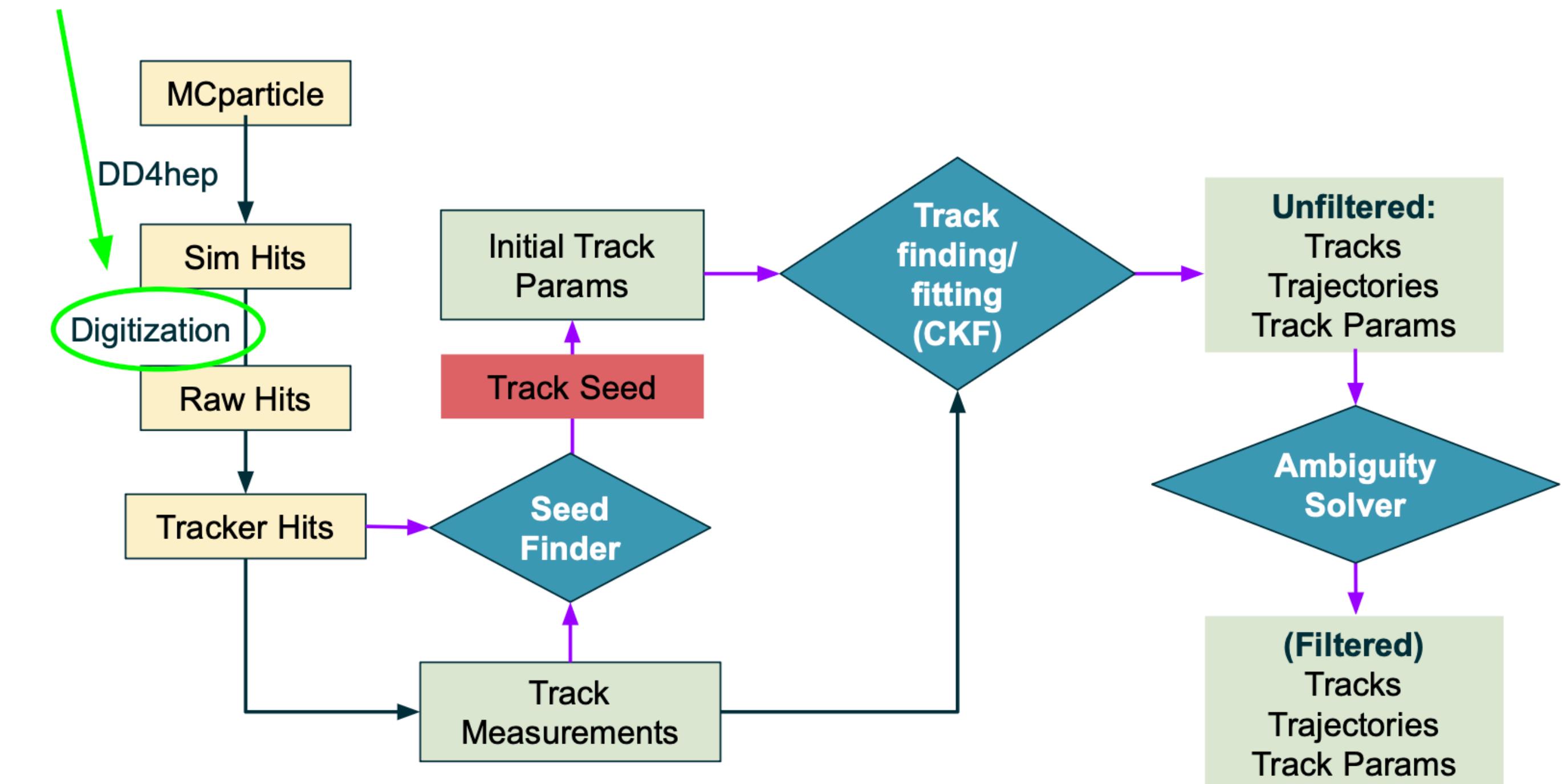
21 July 2025 (Tue.)

Noise Hit Generation for EICrecon

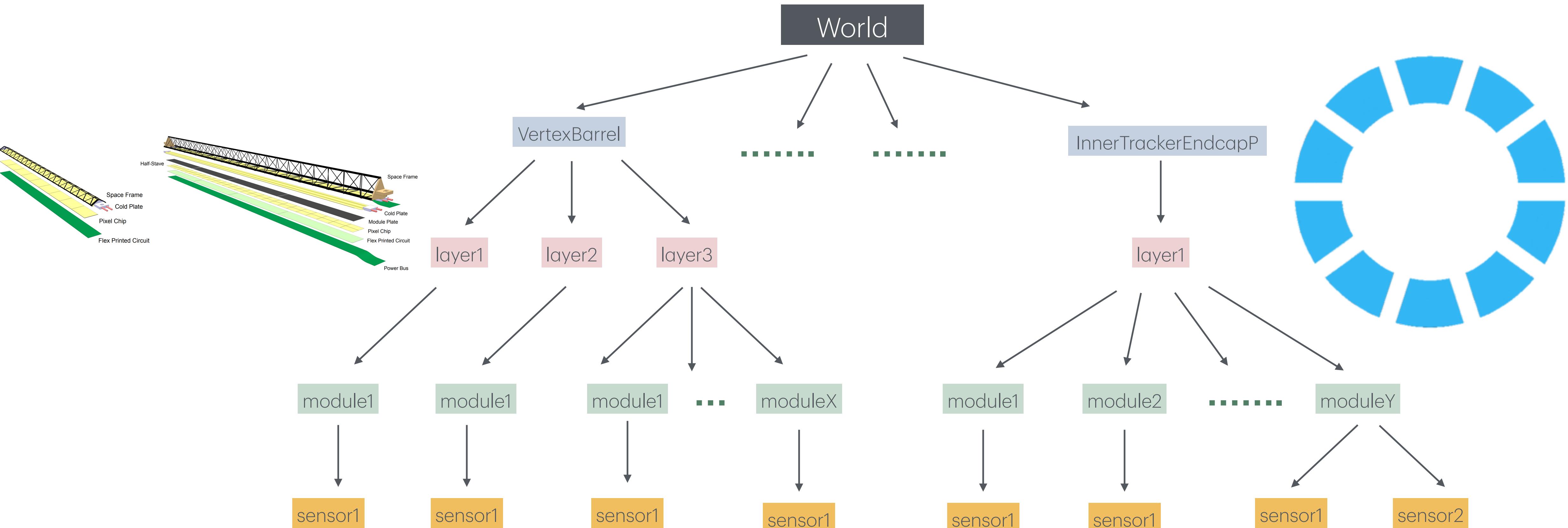
◆ Objective:

- Inject the noise hit of randomly selected sensor pixel
→ active readout unit
- Evaluate the noise effect (fake hit) or tracking performance

Noise Implementation



Readout Unit & CellID



- ◆ **Cell:** smallest unit of the system (detector component) matching to individual readout unit (segmentation)
- ◆ **CellID:** unique ID composed detector structure + readout structure given by 64bit
i.e. For silicon barrel detectors: system:8 layer:4₃module:12 sensor:2 x:16 z:16

Gathering Geometry Information

- ◆ Goal: gathering geometry information of each system with minimum hardcoding input

- ◆ Input:

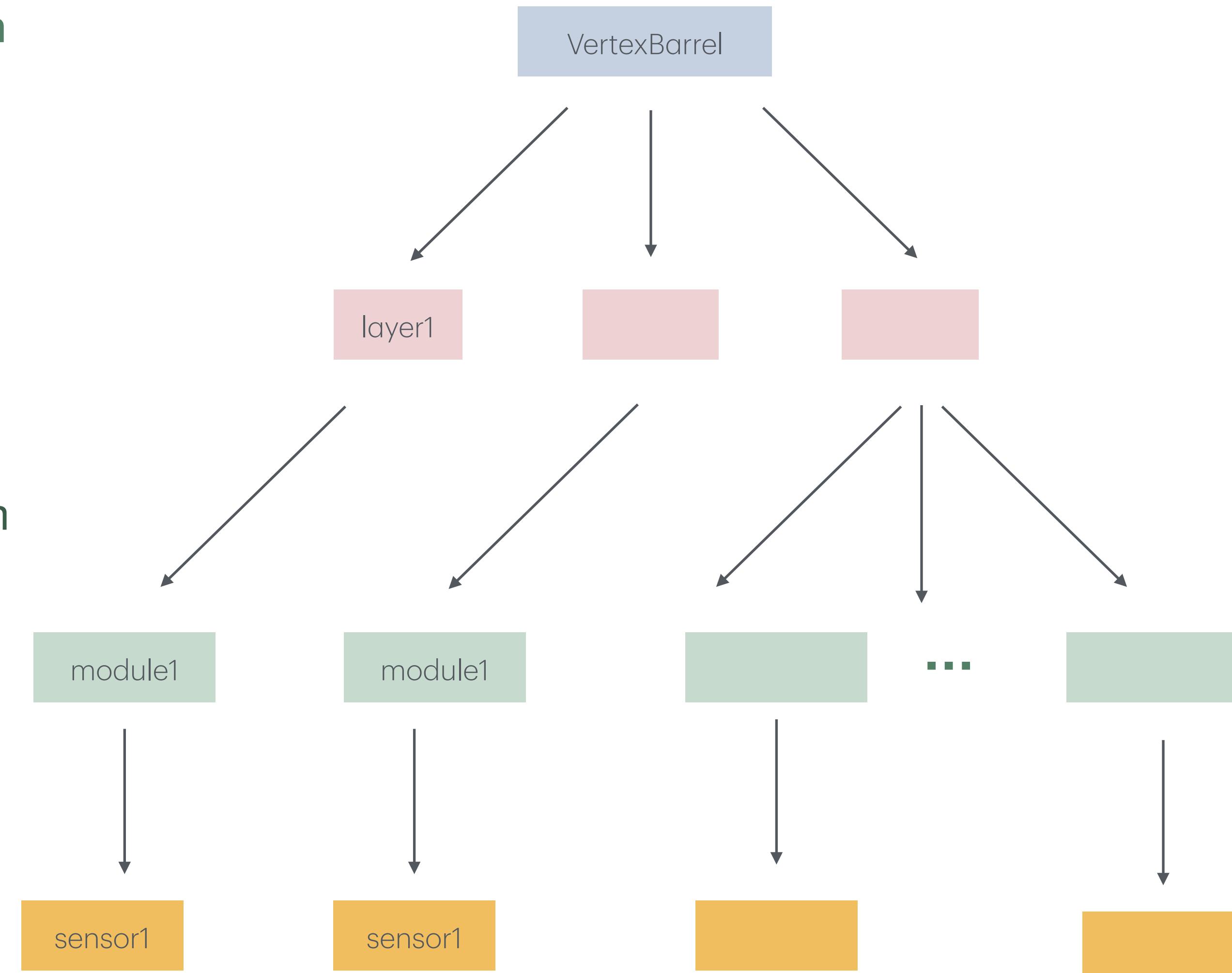
- DD4Hep handler (detector info) accessible in EICrecon via const dd4hep::Detector* m_dd4hepGeo through Service<DD4hep_service> m_geoSvc
- Hit collection (from simulation) created for each system

- ◆ Starting from “system”, identify all unique paths to individual sensitive component via recursively exploring the detector geometry tree

- ◆ Substructure of detector dynamically determined; fields and their effective ranges

system:8 layer:4 module:12 sensor:2 x:16 z:16

$2^{32} \rightarrow O(100-1000)$

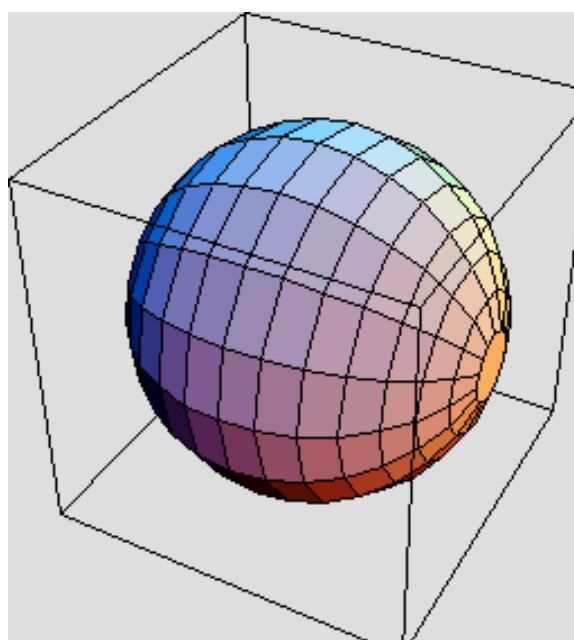


Gathering Local Segmentation Fields

- ◆ Goal: automatically discover the valid range of local coordinates for a single detector component
- ◆ From minimum sensitive volume (assuming that system has single type of detector component), find its bounding box → physical x, y, z dimensions we need to scan
- ◆ Create a sample of valid cellIDs by generating points inside the sensor and checking that each point corresponds to a real cell → (min, max) range for each local segmentation field
 - Cartesian grid: straightforward case; evenly spaced 3D grid of test points inside the bounding box
 - Optimized scanning strategy for “Cylindrical” and “Polar” grids
 - Robustness: segmentation type is unknown or highly complex, it “throws” thousands of random points into the bounding box

system:8 layer:4 module:12 sensor:2 **x:16 z:16**

$2^{32} \rightarrow O(2^{10-14})$

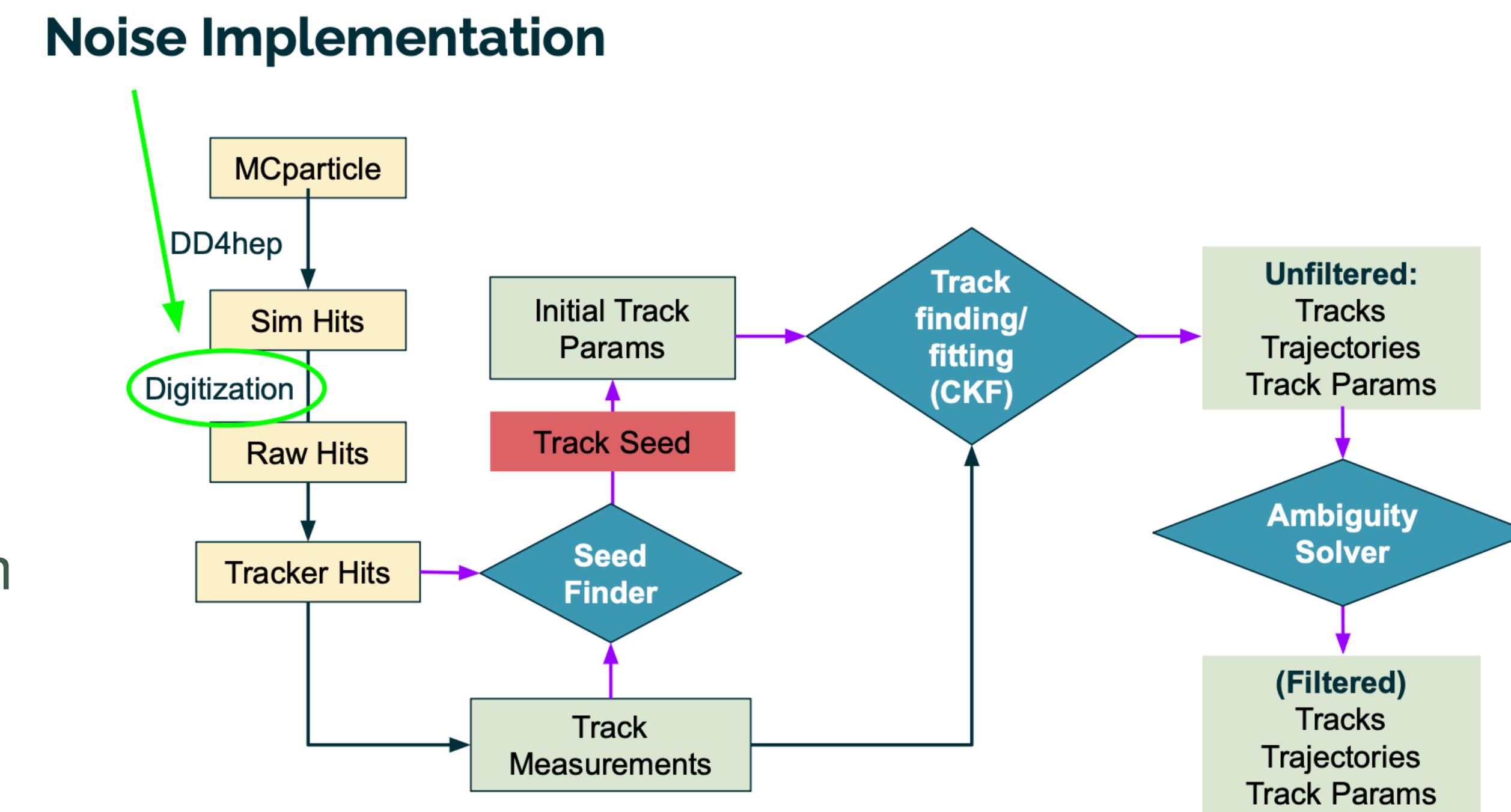


Inject Noise to Hit Collection

♦ CellID Generation: pick a random detector component and local coordinate fields within the valid range

♦ CellID Validation:

- **Uniqueness Check:** verifies the cellID doesn't already exist in the event (either as a real hit or a previously generated noise hit)
- **Position Check:** ensure the combination of random fields corresponds to a real, physical location in the detector



♦ “Random Noise” Factory called after digitalization (`SiliconTrackerDigi_factory`), before hit reconstruction (`TrackerHitReconstruction_factory`)

Random Noise Factory

```
// Digitization
app->Add(new J0mniFactoryGeneratorT<SiliconTrackerDigi_factory>(
    "SiBarrelVertexRawHits", {"VertexBarrelHits"}, [
        {"SiBarrelVertexRawHits", "SiBarrelVertexRawHitAssociations"}, [
            {
                .threshold = 0.54 * dd4hep::keV,
            },
        ],
    ],
    app));
app->Add(new J0mniFactoryGeneratorT<RandomNoise_factory>(
    "NoisySiBarrelVertexRawHits", // 1. The name of the plugin instance
    {"SiBarrelVertexRawHits"}, // 2. The input collection tag
    {"NoisySiBarrelVertexRawHits"}, // 3. The output collection tag
    {.addNoise = true, .n_noise_hits_per_system = 433, .readout_name = "VertexBarrelHits"}, // 4. Configuration parameters
    app));
// Convert raw digitized hits into hits with geometry info (ready for tracking)
app->Add(new J0mniFactoryGeneratorT<TrackerHitReconstruction_factory>(
    "SiBarrelVertexRecHits", {"NoisySiBarrelVertexRawHits"}, {"SiBarrelVertexRecHits"}, [
        {}, // default config
    ],
    app));
```

3 input parameters: transparent when “addNoise” set to “false”

```
struct RandomNoiseConfig {
    // Enable or disable noise injection.
    bool addNoise = true;
    // Average number of noise hits to inject per system.
    // This will be used as the mean for a Poisson distribution.
    int n_noise_hits_per_system = 100;
    std::string readout_name="VertexBarrelHits";
}
```

Silicon Tracker Noise Rate (Shujie)

	A	B	C	D	E	F	G	H	I	J
1	noise rate	5.00E-07	per event per pixel							
2										
3		dim 1 [mm]	dim 2 [mm]	area [mm2]	per RSU					
4	pixel size	2.00E-02	2.00E-02	4.00E-04	1.00E+06					
5										
6		Use nominal geometry from https://eic.jlab.org/Geometry/Detector/Detector-20240515102931.html								
7	Detector name	Barrel layers	R [mm]	L [mm]	Area [mm]	# of pixels	# of noise hits	Total noise hits per parts	This work	from Mito
8	VertexBarrel	L0	36	270	6.11E+04	1.53E+08	76	Inner Barrels	433	433
9		L1	48	270	8.14E+04	2.04E+08	102			
10		L2	120	270	2.04E+05	5.09E+08	254			
11	SagittaSiBarrel	L3	270	540	9.16E+05	2.29E+09	1,145	Outer Barrels	3,784	3,920
12	OuterSiBarrel	L4	420	800	2.11E+06	5.28E+09	2,639			
13										
14	Detector name	Disk	R1 [mm]	R2 [mm]	Area [mm]	# of pixels	# of noise hits			
15	InnerTrackerEndcapN	E-Disk1	36.76	230	3.24E+05	8.10E+08	405	Electron disks (Negative)	6,163	5,910
16	MiddleTrackerEndcapN	E-Disk2	36.76	430	1.15E+06	2.88E+09	1,442			
17	OuterTrackerEndcapN	E-Disk3	36.76	430	1.15E+06	2.88E+09	1,442			
18		E-Disk4	40.06	430	1.15E+06	2.88E+09	1,440			
19		E-Disk5	46.35	430	1.15E+06	2.87E+09	1,435			
20	InnerTrackerEndcapP	H-Disk1	36.76	230	3.24E+05	8.10E+08	405	Hadron disks (Positive)	6,130	5,910
21	MiddleTrackerEndcapP	H-Disk2	36.76	430	1.15E+06	2.88E+09	1,442			
22	OuterTrackerEndcapP	H-Disk3	38.42	430	1.15E+06	2.88E+09	1,441			
23		H-Disk4	54.43	430	1.14E+06	2.86E+09	1,429			
24		H-Disk5	70.14	430	1.13E+06	2.83E+09	1,414			

Summary and outlook

- ◆ New factory “Random Noise” generation is implemented in ElCrecon
- ◆ PR: Random Noise injection factory with its usage in tracker classes #1988
<https://github.com/eic/ElCrecon/pull/1988>
- ◆ For silicon tracker, noise rate calculated by Shujie is implemented
- ◆ Further study - impact of noise on tracking performance - can be done by comparing standard ElCrecon output with “addNoise” on and off